



STTA3006P/PI STTA6006TV1/2

TURBOSWITCH™ ULTRA-FAST HIGH VOLTAGE DIODE

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	30A / 2 x 30A
V_{RRM}	600V
$t_{rr} (typ)$	35ns
$V_F (max)$	1.5V

FEATURES AND BENEFITS

- SPECIFIC TO "FREEWHEEL MODE" OPERATIONS: FREEWHEEL OR BOOSTER DIODE
- ULTRA-FAST AND SOFT RECOVERY
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR
- HIGH FREQUENCY OPERATIONS
- INSULATED PACKAGE : ISOTOP & DOP3I
Electrical insulation : 2500V_{RMS}
Capacitance < 12 pF (DOP3I)
Capacitance < 45 pF (ISOTOP)

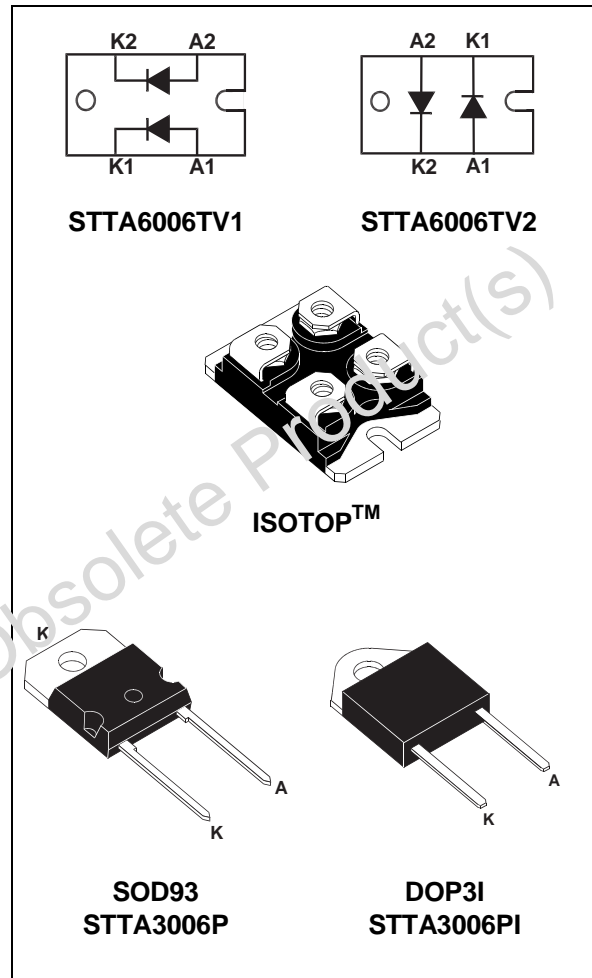
DESCRIPTION

The TURBOSWITCH is a very high performance series of ultra-fast high voltage power diodes from 600V to 1200V. TURBOSWITCH family, drastically cuts losses in both the diode and the associated switching IGBT or MOSFET in all "freewheel mode" operations and is particularly suitable and efficient in motor control freewheel applications and in booster diode applications in power factor control circuitries. Packaged either in ISOTOP, DOP3I or SOD93 these 600V devices are particularly intended for use on 240V domestic mains.

ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	600	V
V_{RSM}	Non repetitive peak reverse voltage	600	V
$I_{F(RMS)}$	RMS forward current	50	A
I_{FRM}	Repetitive peak forward current	$t_p=5\mu s$ F=5kHz square	A
I_{FSM}	Surge non repetitive forward current	$t_p=10$ ms sinusoidal	A
T_j	Maximum operating junction temperature	150	°C
T_{stg}	Storage temperature range	-65 to 150	°C

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THERMAL AND POWER DATA (Per diode)

Symbol	Parameter	Test conditions		Value	Unit
R _{th(j-c)}	Junction to case thermal resistance	ISOTOP	Per diode	1.4	°C/W
			Total	0.75	
		DOP3I		1.8	
		SOD93		1.2	
R _{th(c)}		ISOTOP	Coupling	0.1	°C/W
P ₁	Conduction power dissipation I _{F(AV)} = 30A δ = 0.5	ISOTOP	T _c = 74°C	54	W
		DOP3I	T _c = 52°C		
		SOD93	T _c = 85°C		
P _{max}	Total power dissipation P _{max} = P ₁ + P ₃ (P ₃ = 10% P ₁)	ISOTOP	T _c = 66°C	60	W
		DOP3I	T _c = 42°C		
		SOD93	T _c = 78°C		

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V _{F*}	Forward voltage drop	I _F = 30A	T _j = 25°C			1.75	V
			T _j = 125°C		1.25	1.5	V
I _{R**}	Reverse leakage current	V _R = 0.8 × V _{RRM}	T _j = 25°C T _j = 125°C		3	150 8	μA mA
V _{to}	Threshold voltage	I _p < 3.I _{AV}	T _j = 125°C			1.15	V
r _d	Dynamic resistance					11	mΩ

Test pulses : * t_p = 380 μs, δ < 2%

** t_p = 5 ms, δ < 2%

To evaluate the maximum conduction losses use the following equation :

$$P = V_{to} \times I_{F(AV)} + r_d \times I_{F(RMS)}^2$$

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t _{rr}	Reverse recovery time	T _j = 25°C I _F = 0.5 A I _R = 1A I _{rr} = 0.25A I _F = 1 A dI _F /dt = -50A/μs V _R = 30V		35	65	ns
I _{RM}	Maximum reverse recovery current	T _j = 125°C V _R = 400V I _F = 30A dI _F /dt = -240 A/μs dI _F /dt = -500 A/μs		20	19	A
S factor	Softness factor	T _j = 125°C V _R = 400V I _F = 30A dI _F /dt = -500 A/μs		0.40		-

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	$T_j = 25^\circ\text{C}$ $I_F = 30\text{A}$, $dI_F/dt = 240\text{ A}/\mu\text{s}$ measured at, $1.1 \times V_{Fmax}$			600	ns
V_{FP}	Peak forward voltage	$T_j = 25^\circ\text{C}$ $I_F = 30\text{A}$, $dI_F/dt = 240\text{ A}/\mu\text{s}$			12	V

Fig. 1: Conduction losses versus average current.

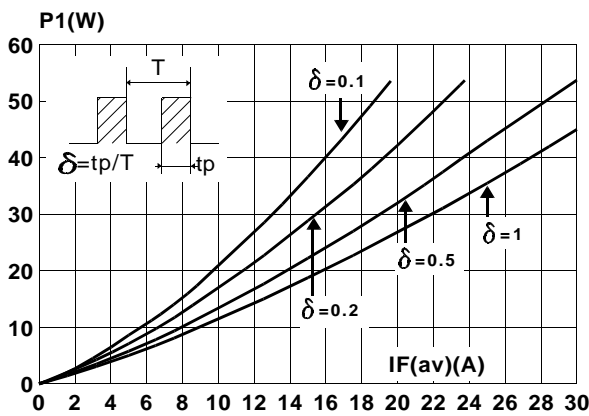


Fig. 2: Forward voltage drop versus forward current.

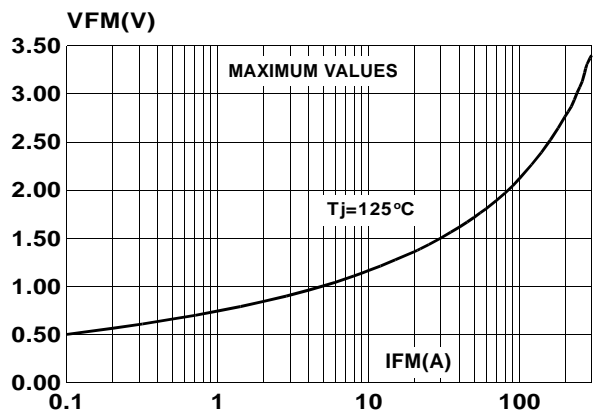


Fig. 3: Relative variation of thermal transient impedance junction to case versus pulse duration.

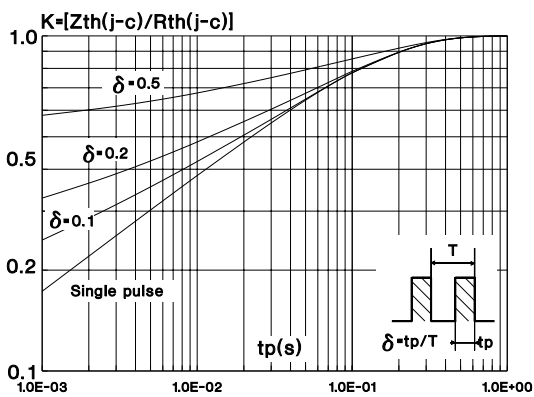


Fig. 4: Peak reverse recovery current versus dIF/dt.

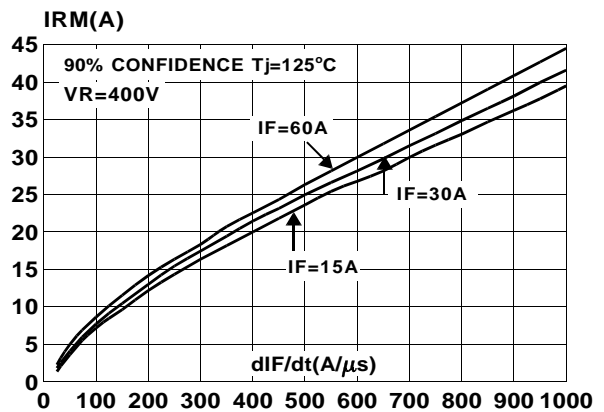


Fig. 5: Reverse recovery time versus dI_F/dt .

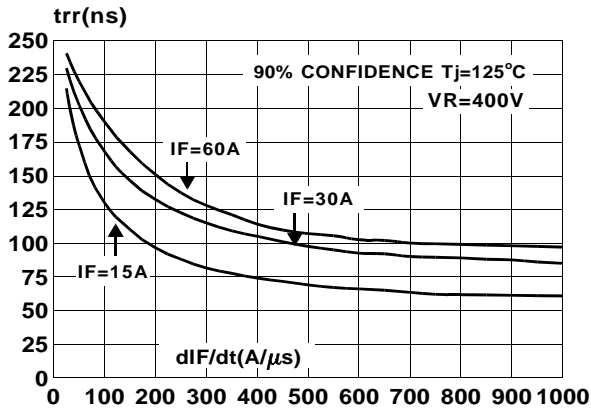


Fig. 6: Softness factor (t_b/t_a) versus dI_F/dt .

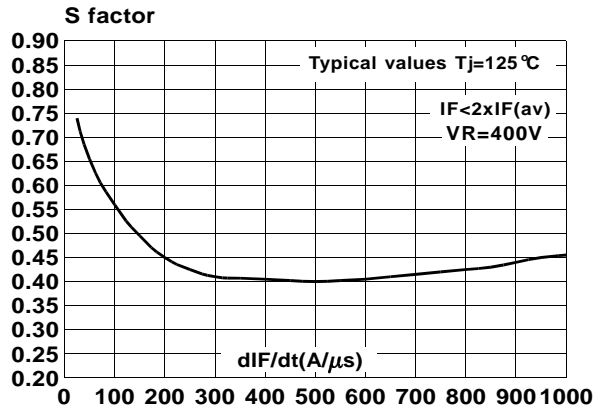


Fig. 7: Relative variation of dynamic parameters versus junction temperature (reference $T_j=125^\circ C$).

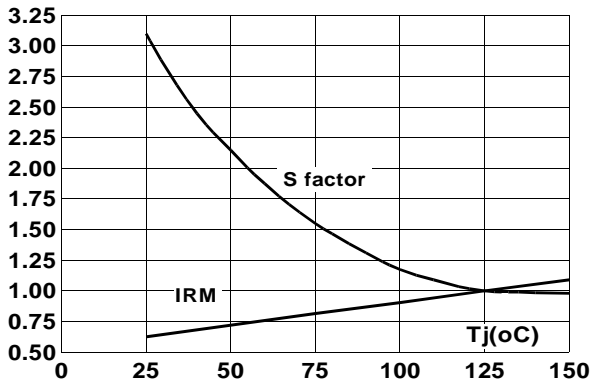


Fig. 8: Transient peak forward voltage versus dI_F/dt .

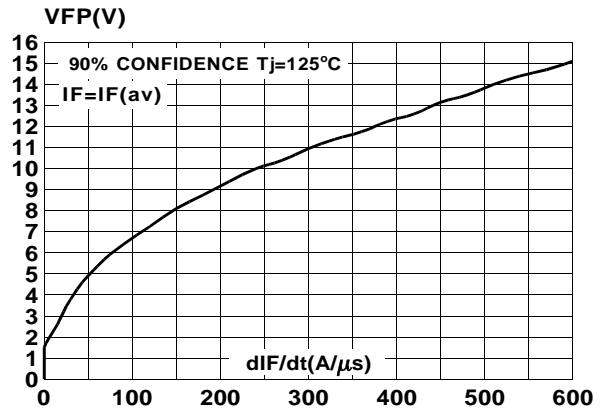
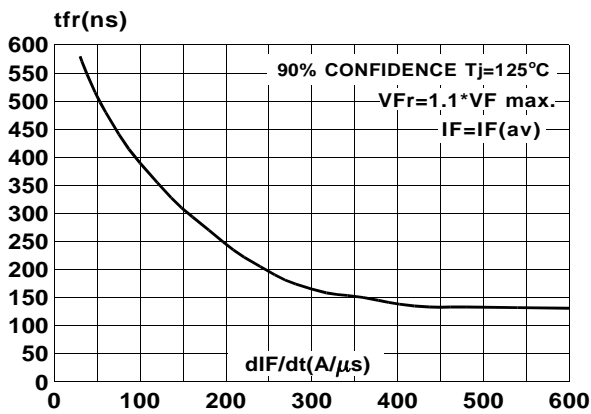


Fig. 9: Forward recovery time versus dI_F/dt .



APPLICATION DATA

The TURBOSWITCH is especially designed to provide the lowest overall power losses in any "FREEWHEEL Mode" application (Fig.A) considering both the diode and the companion

transistor, thus optimizing the overall performance in the end application. The way of calculating the power losses is given below:

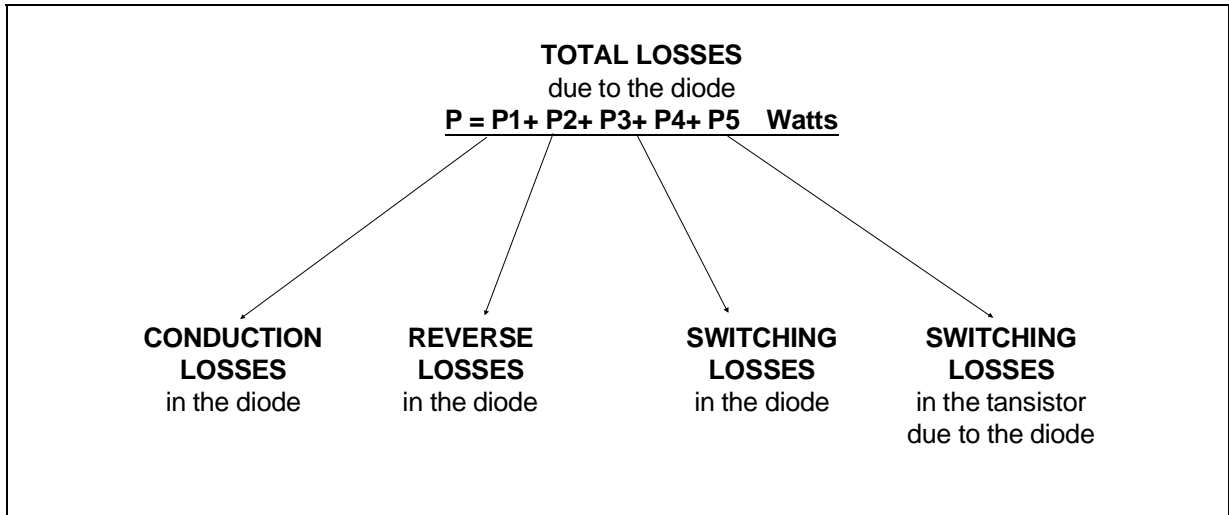
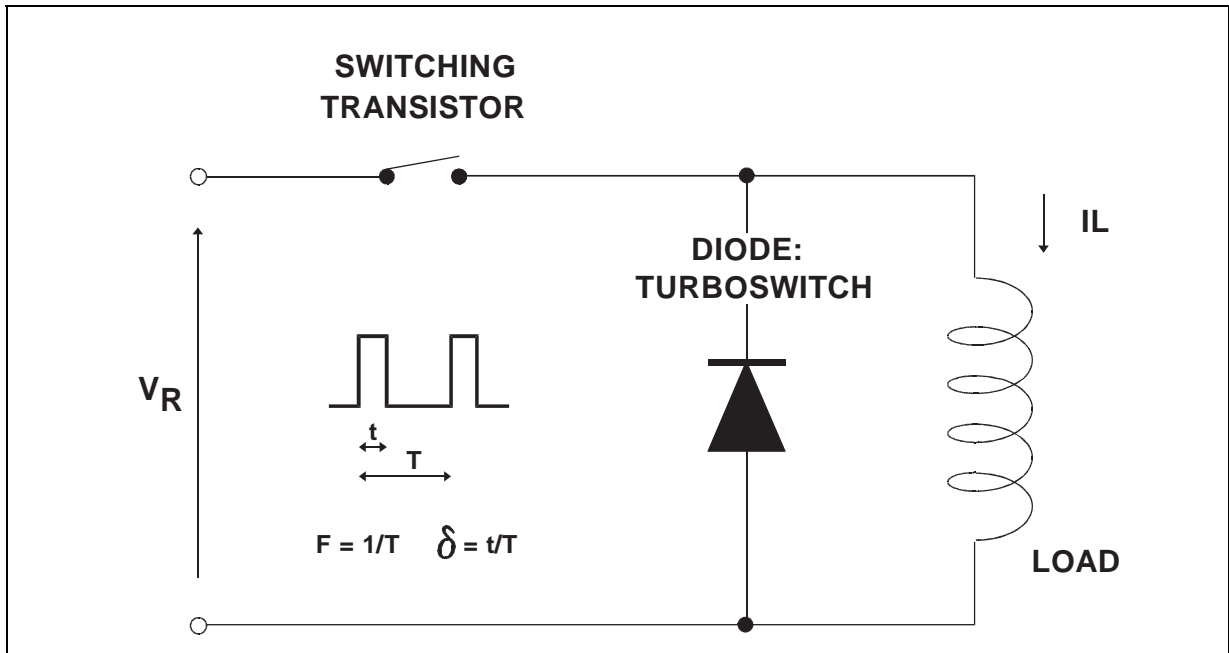
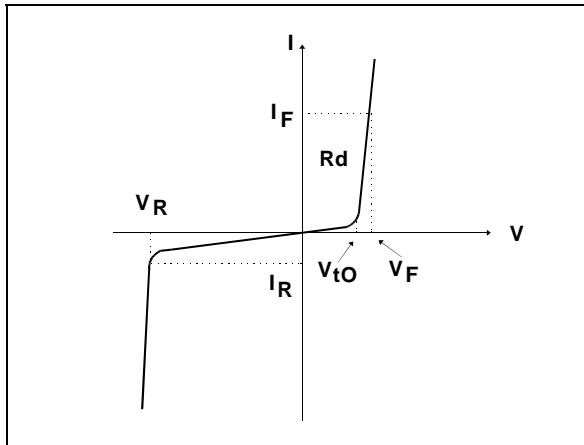


Fig. A : "FREEWHEEL" MODE.



APPLICATION DATA (Cont'd)

Fig. B: STATIC CHARACTERISTICS



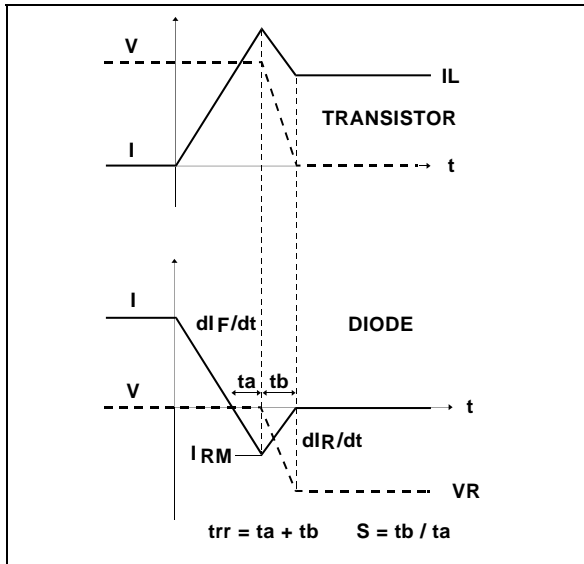
Conduction losses :

$$P1 = V_{t0} \cdot I_F(AV) + R_d \cdot I_F^2(RMS)$$

Reverse losses :

$$P2 = V_R \cdot I_R \cdot (1 - \delta)$$

Fig. C: TURN-OFF CHARACTERISTICS



Turn-on losses :

(in the transistor, due to the diode)

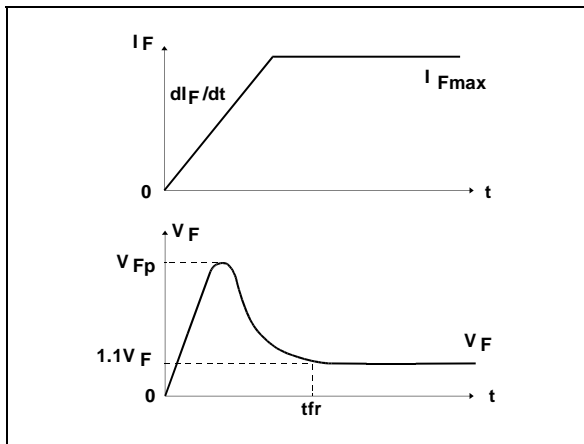
$$P5 = \frac{V_R \times I_{RM}^2 \times (3 + 2 \times S) \times F}{6 \times dI_F/dt} + \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \times dI_F/dt}$$

Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM}^2 \times S \times F}{6 \times dI_F/dt}$$

P3 and P5 are suitable for power MOSFET and IGBT

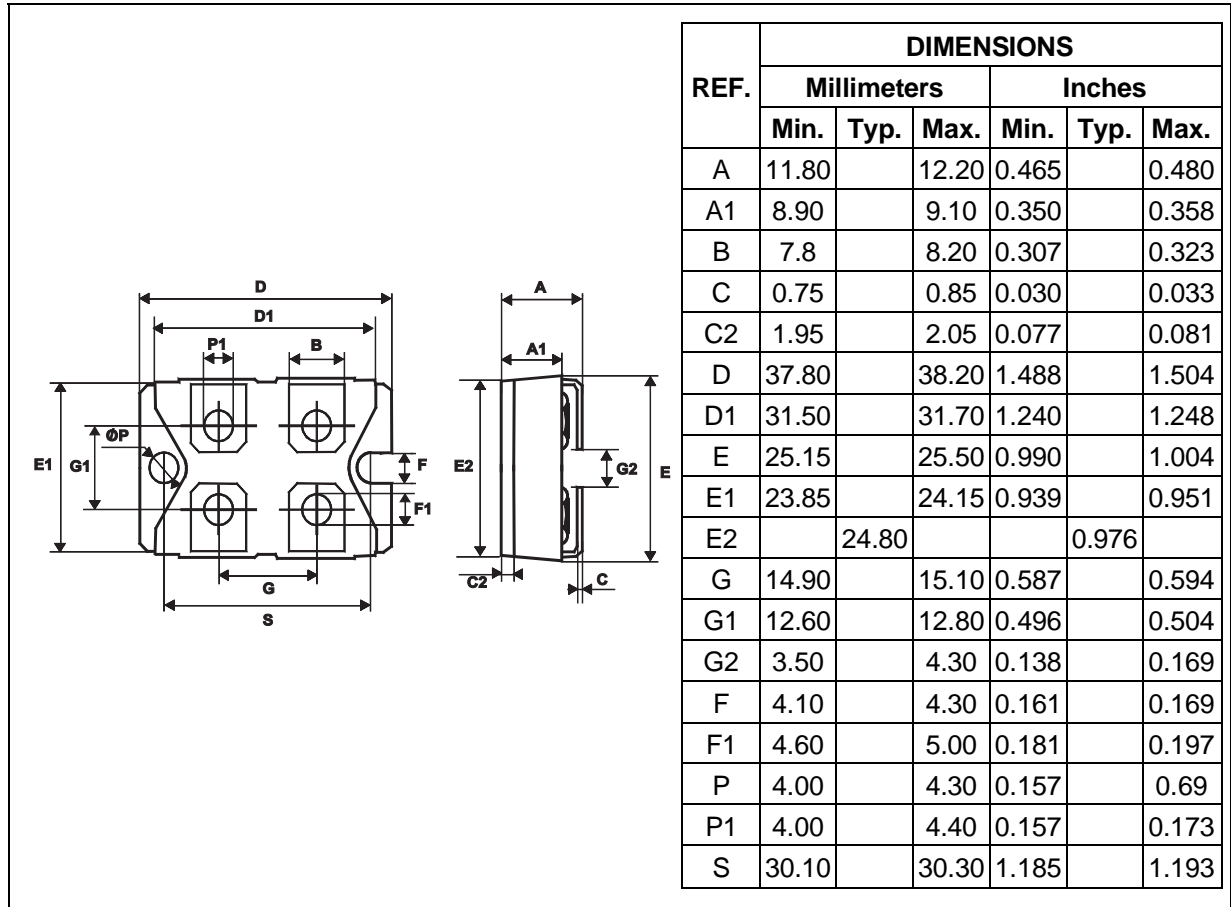
Fig. D: TURN-ON CHARACTERISTICS



Turn-on losses :

$$P4 = 0.4 (V_{FP} - V_F) \cdot I_{Fmax} \cdot t_{fr} \cdot F$$

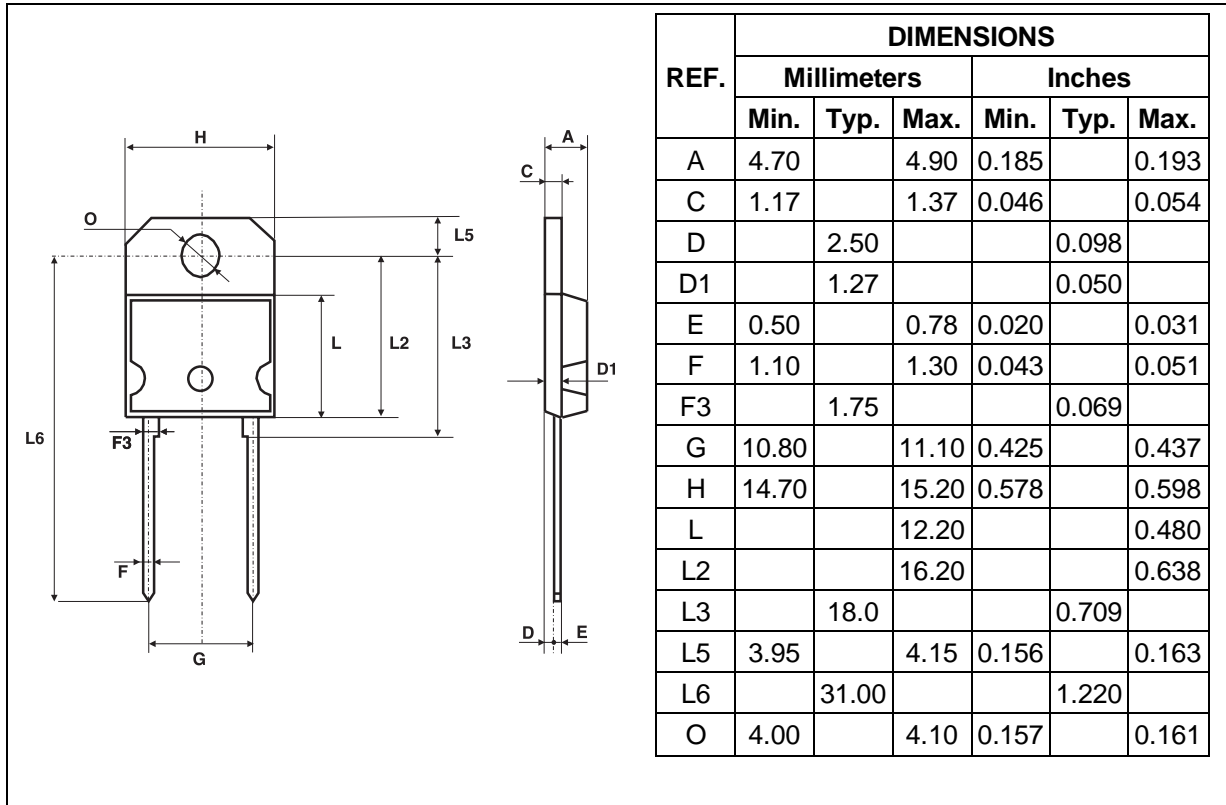
PACKAGE MECHANICAL DATA
ISOTOP



Cooling method : by conduction (C)

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PACKAGE MECHANICAL DATA
SOD93



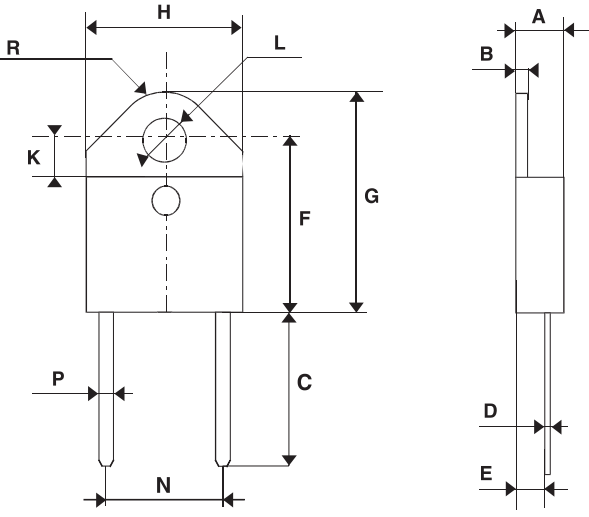
Cooling method : by conduction (C)

Recommended torque value : 0.8 m.N

Maximum torque value : 1m.N

PACKAGE MECHANICAL DATA
 DOP3I

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	1.45	1.55	0.057	0.061
C	14.35	15.60	0.565	0.614
D	0.5	0.7	0.020	0.028
E	2.7	2.9	0.106	0.114
F	15.8	16.5	0.622	0.650
G	20.4	21.1	0.815	0.831
H	15.1	15.5	0.594	0.610
K	3.4	3.65	0.134	0.144
L	4.08	4.17	0.161	0.164
N	10.8	11.3	0.425	0.444
P	1.20	1.40	0.047	0.055
R	4.60 typ.		0.181 typ.	



Cooling method : by conduction (C)

Recommended torque value : 0.8 m.N

Maximum torque value : 1 m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA6006P	STTA6006P	SOD93	3.79g	30	Tube
STTA6006PI	STTA6006PI	DOP3I	4.52g	30	Tube
STTA6006TV1	STTA6006TV1	ISOTOP	27g without screws	10	Tube
STTA6006TV2	STTA006TV2	ISOTOP		10	Tube

■ Epoxy meets UL94,V0

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